



HIRP2013X10-B40

SMD Type 850nm Infrared Emitter

Features

- Small double-end package
- Viewing Angle= $\pm 70^\circ$
- High reliability
- Good spectral matching to Si photo detector
- RoHS compliance

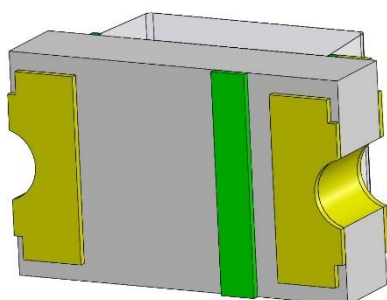
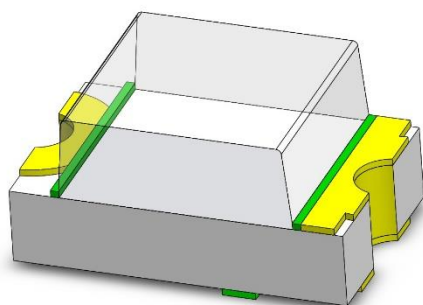
Applications

- Infrared sensor

Description

The HIRP2013X10-B40 is a GaAlAs infrared LED housed in a miniature SMD package. The device has a peak wavelength of 850nm LED spectrally matched with phototransistor or photodiode.

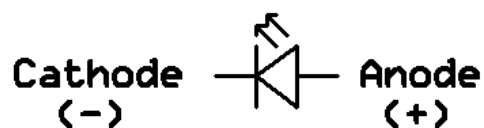
Package Outline



Anode

Cathode

Schematic



**Absolute Maximum Rating at 25°C**

Symbol	Parameters	Ratings	Units	Notes
I _F	Continuous Forward Current	70	mA	
I _{FP}	Peak Forward Current	0.7	A	1
V _R	Reverse Voltage	5	V	
T _{opr}	Operating Temperature	-40 ~ +85	°C	
T _{stg}	Storage Temperature	-40 ~ +100	°C	
T _{sol}	Soldering Temperature	260	°C	2
P _D	Power Dissipation at(or below) 25°C Free Air Temperature	140	mW	

Electro-Optical Characteristics *TA = 25°C (unless otherwise specified)***Optical Characteristics**

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
I _e	Radiant Intensity	I _F =20mA	1.60	2.20	3.20	mW/sr	3
		I _F =70mA	-	8.0	-		
λ _p	Peak Wavelength	I _F =20mA	-	850	-	nm	
Δλ	Spectral Bandwidth	I _F =20mA	-	30	-	nm	
θ _{1/2}	Angle of Half Intensity	I _F =20mA	-	±70	-	deg	

Electrical Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
V _F	Forward Voltage	I _F =20mA	1.2	1.4	1.7	V	
		I _F =70mA	1.3	1.5	2.0		
		I _F =0.5A, T _p =3ms	1.5	2.0	2.4		
		I _F =1A, T _p =3ms	1.8	2.4	3.2		
I _R	Reverse Current	V _R =5V	-	-	10	μA	

Notes:

- I_{FP} Conditions--Pulse Width ≤ 100μs and Duty ≤ 1%.
- Soldering time ≤ 5 seconds.
- I_e Bin Rank : (Tolerance of Radiant Intensity : ±10%)

Bin Code	AB	CD
Min	1.60	2.40
Max	2.40	3.20



Typical Characteristic Curves

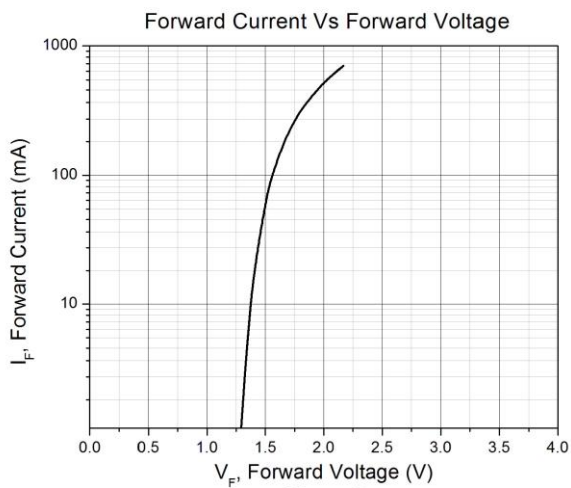


Figure 1

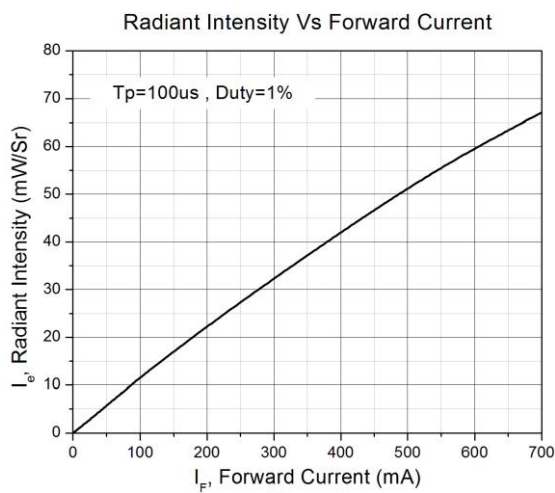


Figure 2

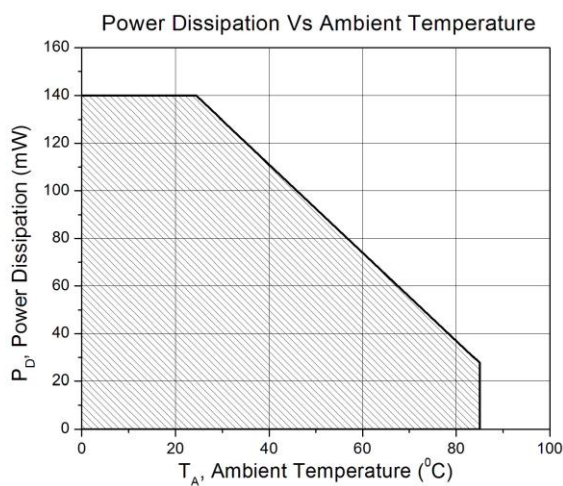


Figure 3

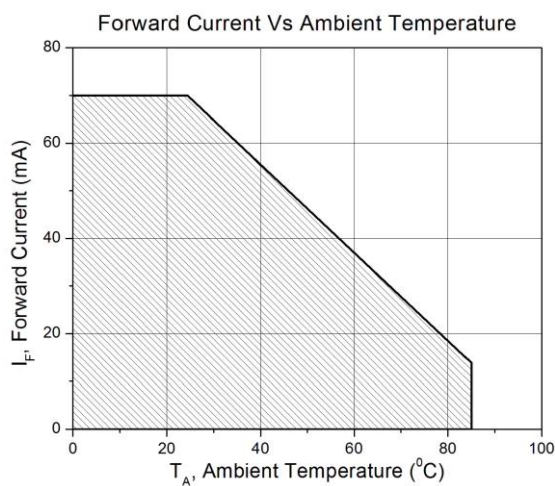


Figure 4

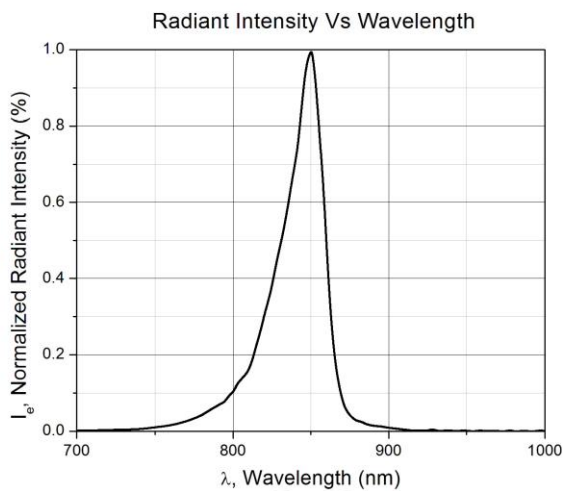
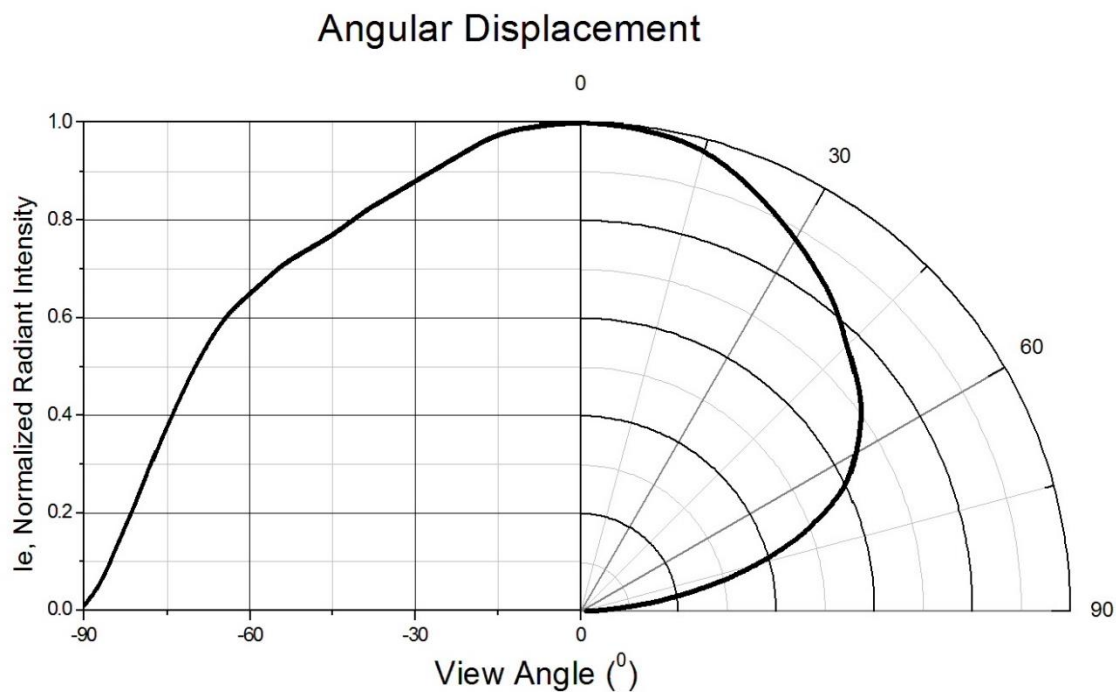


Figure 5



Typical Characteristic Curves

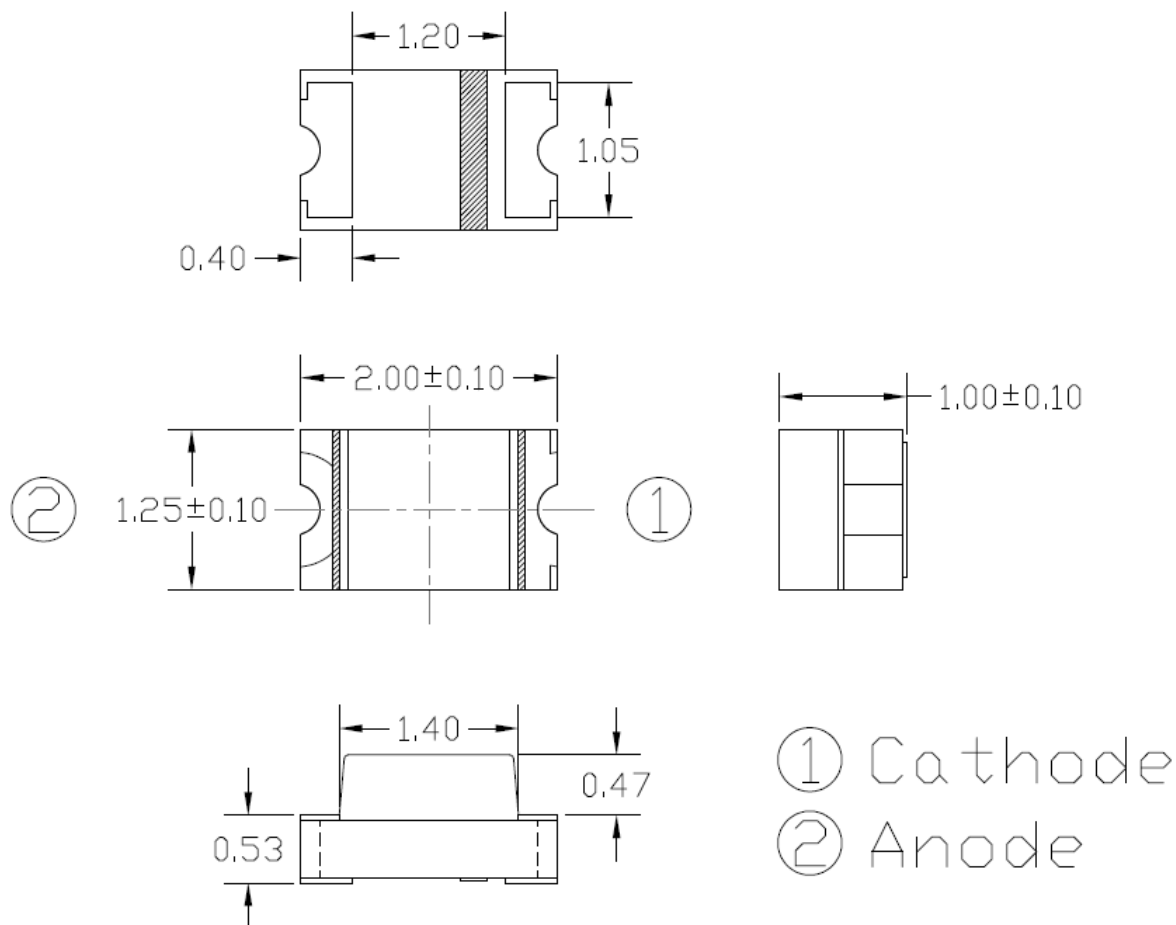




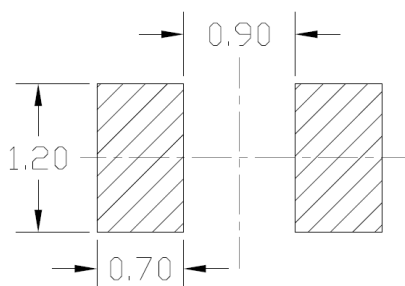
HIRP2013X10-B40

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Package Dimension *All dimensions are in mm, unless otherwise stated*



Recommended Soldering Mask *All dimensions are in mm, unless otherwise stated*



Ordering Information

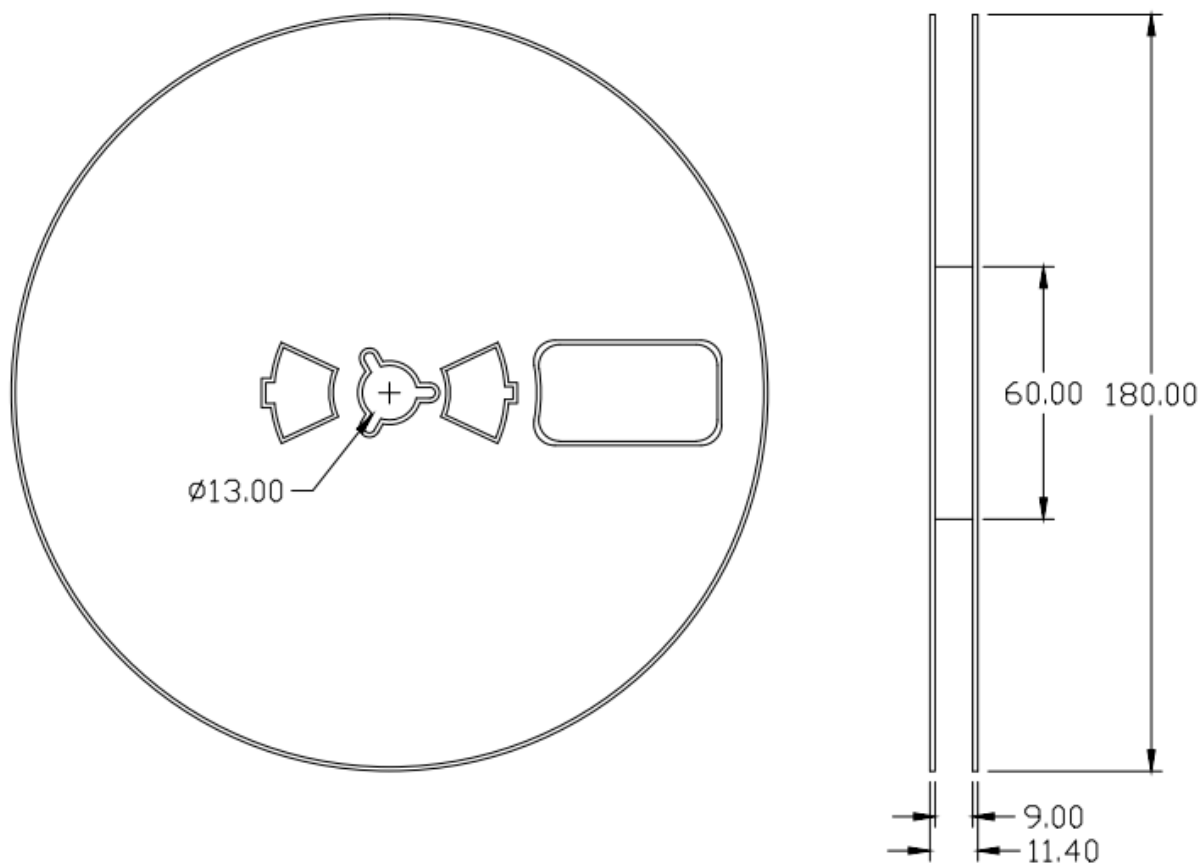
Part Number	Description	Quantity
HIRP2013X10-B40	Tape & Reel	3000 Pcs



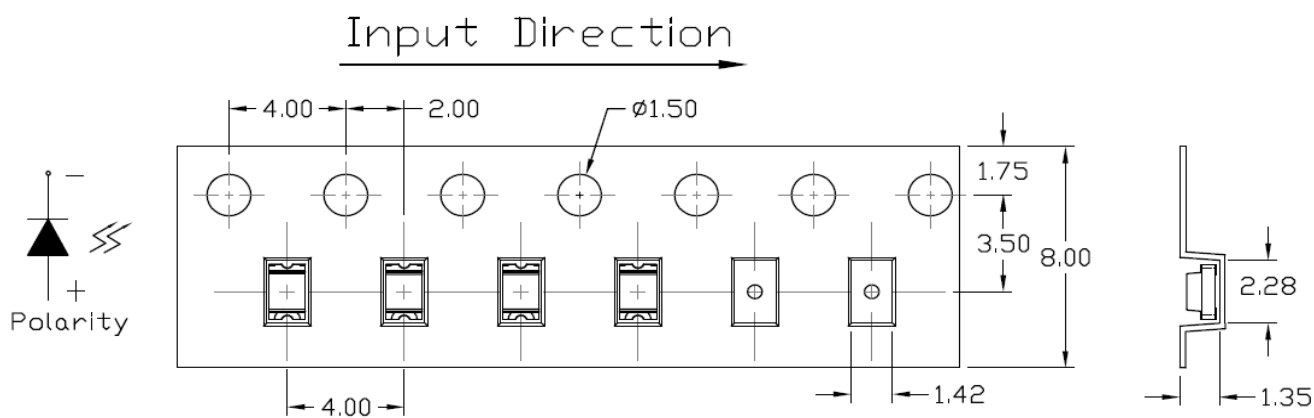
HIRP2013X10-B40

SMD Type 850nm Infrared Emitter

Reel Dimension *All dimensions are in mm, unless otherwise stated*



Tape Dimension *All dimensions are in mm, unless otherwise stated*

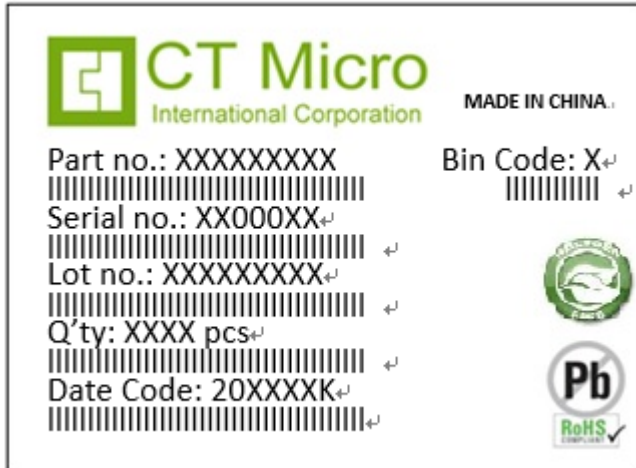




HIRP2013X10-B40

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Label Form Specification



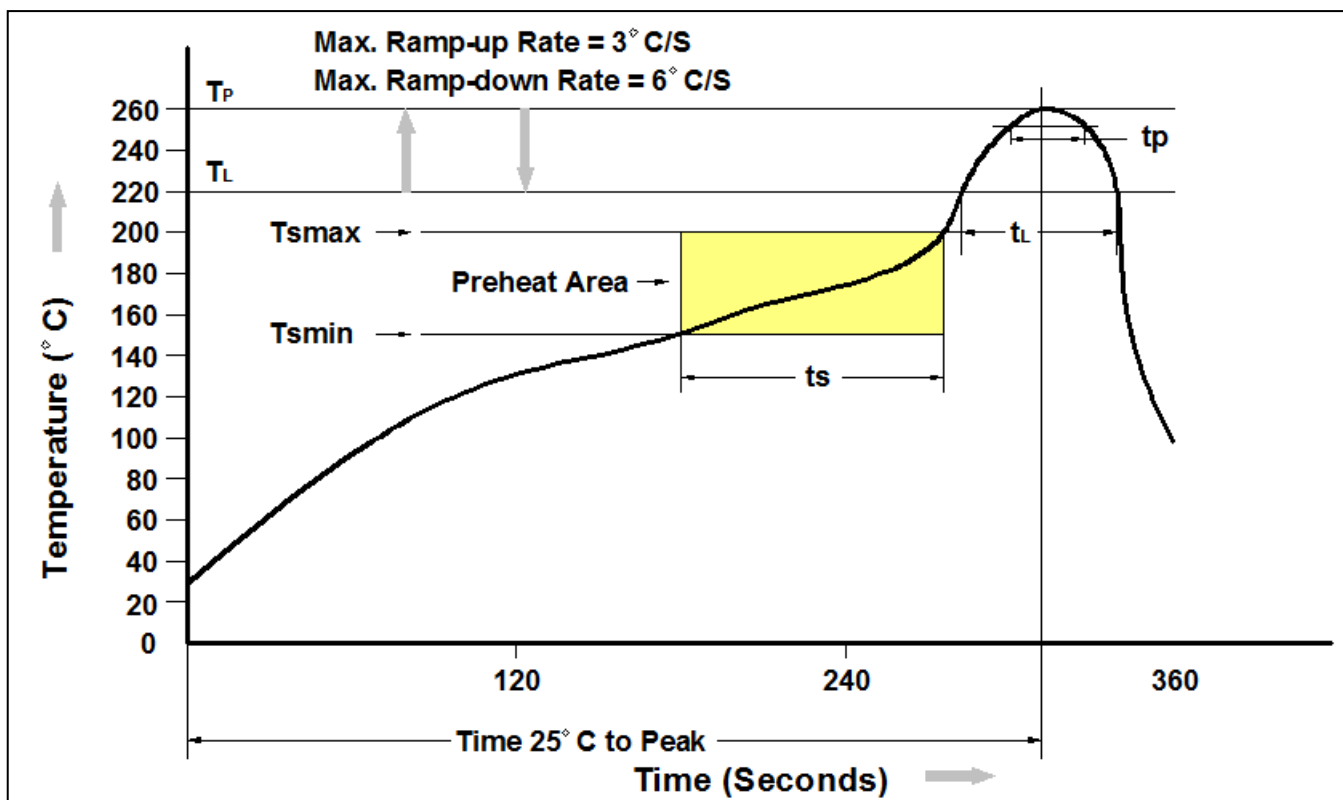
Part no: CTM Production Number
 Serial no: Production Number
 Lot no: Lot number
 Q'ty: Packing Quantity
 Date Code: Manufacture Date
 Bin Code: 1e Ranks
 MADE IN CHINA: Production Place

Storage Condition

1. Do not open moisture proof bag before the products are ready to use.
2. The moisture barrier bag should be stored at 30°C and 90%R.H. max. before opening.
Shelf life of non-opened bag is 12 months after the bag sealing date.
3. After opening the moisture barrier bag floor life is 168h at 30°C/60%RH. max. Unused LEDs should be resealed into moisture barrier bag. (Refer to J-STD-020 Standard)
4. If the moisture absorbent material has faded away or the LEDs have exceeded the storage time, baking treatment should be performed using the J-STD-033 Standard conditions.



Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T _{min})	150°C
Temperature Max. (T _{max})	200°C
Time (t _s) from (T _{min} to T _{max})	60-120 seconds
Ramp-up Rate (t _L to t _P)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



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